











LMV321A, LMV324A, LMV358A

SBOS923F - DECEMBER 2017 - REVISED JANUARY 2020

LMV3xxA Low-Voltage Rail-to-Rail Output Operational Amplifiers

Features

Low input offset voltage: ±1 mV

Rail-to-rail output

Unity-gain bandwidth: 1 MHz Low broadband noise: 30 nV/√Hz

Low input bias current: 10 pA Low quiescent current: 70 µA/Ch

Unity-gain stable

Internal RFI and EMI filter

Operational at supply voltages as low as 2.5 V

Easier to stabilize with higher capacitive load due to resistive open-loop output impedance

Extended temperature range: -40°C to 125°C

Applications

- Smoke detectors
- Motion detectors
- Wearable devices
- Large and small appliances
- **EPOS**
- Barcode scanners
- Sensor signal conditioning
- Power modules
- Personal electronics
- Active filters
- HVAC: heating, ventilating, and air conditioning
- Motor control: AC induction
- Low-side current sensing

3 Description

The LMV3xxA family includes single - (LMV321A), dual - (LMV358A), and quad-channel (LMV324A) lowvoltage (2.5 V to 5.5 V) operational amplifiers (op amps) with rail-to-rail output swing capabilities. These op amps provide a cost-effective solution for spaceconstrained applications such as large appliances, smoke detectors, and personal electronics where lowvoltage operation and high capacitive-load drive are required. The capacitive-load drive of the LMV3xxA family is 500 pF, and the resistive open-loop output impedance makes stabilization easier with much higher capacitive loads. These op amps are designed specifically for low-voltage operation (2.5 V to 5.5 V) with performance specifications similar to the LMV3xx devices.

The robust design of the LMV3xxA family simplifies circuit design. The op amps feature unity-gain stability, an integrated RFI and EMI rejection filter, and no-phase reversal in overdrive conditions.

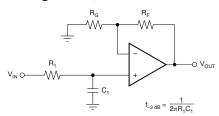
The LMV3xxA family is available in industry-standard packages such as SOIC, MSOP, SOT-23, and TSSOP packages.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
LMV321A	SOT-23 (5)	1.60 mm × 2.90 mm		
LIVIV 32 IA	SC70 (5)	1.25 mm × 2.00 mm		
	SOIC (8)	3.91 mm × 4.90 mm		
LMV358A	TSSOP (8)	3.00 mm × 4.40 mm		
LIVIV336A	SOT-23 (8)	1.60 mm × 2.90 mm		
	VSSOP (8)	3.00 mm × 3.00 mm		
LMV324A	SOIC (14)	8.65 mm × 3.91 mm		
LIVI V 324A	TSSOP (14)	4.40 mm × 5.00 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Single-Pole, Low-Pass Filter



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_E}{R_G}\right) \left(\frac{1}{1 + sR_1C_1}\right)$$



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nanges from Revision D (November 2016) to Revision E	han	nges from Revision D (November 2018) to Revision E		Pa	age
Added SOT-23 (8) package to Device Information	Ad	dded SOT-23 (8) package to Device Information			1
Added SOT-23 (8) (DDF) package to the Pin Configuration and Functions section	Αd	dded SOT-23 (8) (DDF) package to the Pin Configuration	n and Fun	ctions section	4

Changes from Revision C (August 2018) to Revision D

Page

Changed the document status From: Production Data/Mixed To: Production Data
 Changed LMV321A SOT-23 and SC70 packages From: Preview To: Production
 Changed LMV324A SOIC and TSSOP packages From: Preview To: Production
 Deleted DBV (SOT-23) and DCK (SC70) package preview note from the LM321A Thermal Information table

Changes from Revision B (June 2018) to Revision C

Page

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Changes from Revision A (May 2018) to Revision B	Page
Added SOT-23 package to Device Information table	1
Added SC70 package to Device Information table	1
Added TSSOP-8 package to Device Information table	1
Added SOIC-14 package to Device Information table	
Added TSSOP-14 package to Device Information table	1
Added Thermal Information: LMV321A	7
Added Thermal Information: LMV324A	
Changes from Original (December 2017) to Revision A	Page
Changed device status from Advance Information to Production Data/Mixed Status	
Added DGK and PW package to the LMV358A Thermal Information table	7

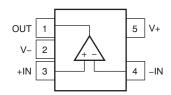
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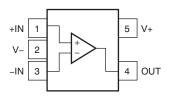


5 Pin Configuration and Functions

LMV321A DBV Package 5-Pin SOT-23 Top View



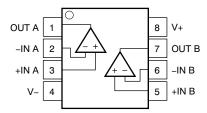
LMV321A DCK, LMV321AU DBV Package 5-Pin SC70, SOT-23 Top View



Pin Functions: LMV321A

PIN		1/0	DECODIDATION		
NAME	DBV	DCK, DBV (U)	1/0	DESCRIPTION	
-IN	4	3	I	Inverting input	
+IN	3	1	I	Noninverting input	
OUT	1	4	0	Output	
V-	2	2	_	Negative (lowest) supply or ground (for single-supply operation)	
V+	5	5	_	Positive (highest) supply	

LMV358A D, DDF, DGK, PW Packages 8-Pin SOIC, VSSOP, TSSOP Top View

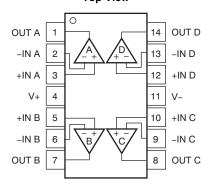


Pin Functions: LMV358A

PIN		1/0	DECORIDATION		
NAME	NO.	1/0	DESCRIPTION		
–IN A	2	I	Inverting input, channel A		
+IN A	3	I	Noninverting input, channel A		
–IN B	6	- 1	rerting input, channel B		
+IN B	5	- 1	ninverting input, channel B		
OUT A	1	0	Output, channel A		
OUT B	7	0	Output, channel B		
V-	4	_	egative (lowest) supply or ground (for single-supply operation)		
V+	8	_	Positive (highest) supply		



LMV324A D, PW Packages 14-Pin SOIC, TSSOP Top View



Pin Functions: LMV324A

	PIN		DESCRIPTION		
NAME	NO.	1/0	DESCRIPTION		
–IN A	2	1	Inverting input, channel A		
+IN A	3	1	Noninverting input, channel A		
–IN B	6	1	Inverting input, channel B		
+IN B	5	I	Noninverting input, channel B		
–IN C	9	I	Inverting input, channel C		
+IN C	10	1	ninverting input, channel C		
–IN D	13	1	Inverting input, channel D		
+IN D	12	- 1	Noninverting input, channel D		
OUT A	1	0	Output, channel A		
OUT B	7	0	Output, channel B		
OUT C	8	0	Output, channel C		
OUT D	14	0	Output, channel D		
V-	11	_	Negative (lowest) supply or ground (for single-supply operation)		
V+	4	_	Positive (highest) supply		

Product Folder Links: LMV321A LMV324A LMV358A



6 Specifications

6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
Supply voltage, ([V+] - [V-])		0	6	V	
	Voltage ⁽²⁾	Common-mode	(V-) - 0.5	(V+) + 0.5	V
Signal input pins	voitage (=/	Differential		(V+) - (V-) + 0.2	V
	Current ⁽²⁾		-10	10	mA
Output short-circuit (3)				Continuous	
Operating, T _A			-55	150	°C
Operating junction temperature, T _J			150	°C	
Storage temperature, T _{stg}		-65	150	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
.,	Clastractatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	\/
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _S	Supply voltage	2.5	5.5	٧
T _A	Specified temperature	-40	125	°C

⁽²⁾ Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.

⁽³⁾ Short-circuit to ground, one amplifier per package.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information: LMV321A

		LMV3	LMV321A		
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	DCK (SC70)	UNIT	
		5 PINS	5 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	232.8	239.6	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	153.8	148.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	100.9	82.3	°C/W	
ΨЈТ	Junction-to-top characterization parameter	77.2	54.5	°C/W	
ΨЈВ	Junction-to-board characterization parameter	100.4	81.8	°C/W	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

6.5 Thermal Information: LMV358A

		LMV358A				
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	PW (TSSOP)	DDF (SOT-23)	UNIT
		8 PINS	8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	147.4	201.2	205.8	183.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	94.3	85.7	106.7	112.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	89.5	122.9	133.9	98.2	°C/W
ΨЈТ	Junction-to-top characterization parameter	47.3	21.2	34.4	18.8	°C/W
ΨЈВ	Junction-to-board characterization parameter	89	121.4	132.6	97.6	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

6.6 Thermal Information: LMV324A

		LMV	LMV324A				
	THERMAL METRIC ⁽¹⁾	D (SOIC)	PW (TSSOP)	UNIT			
		14 PINS	8 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102.1	148.3	°C/W			
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	56.8	68.1	°C/W			
$R_{\theta JB}$	Junction-to-board thermal resistance	58.5	92.7	°C/W			
ΨЈТ	Junction-to-top characterization parameter	20.5	16.9	°C/W			
ΨЈВ	Junction-to-board characterization parameter	58.1	91.8	°C/W			

⁽¹⁾ For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

Product Folder Links: LMV321A LMV324A LMV358A



6.7 Electrical Characteristics

For $V_S = (V+) - (V-) = 2.5 \text{ V}$ to 5.5 V (±0.9 V to ±2.75 V), $T_A = 25^{\circ}\text{C}$, $R_L = 10 \text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

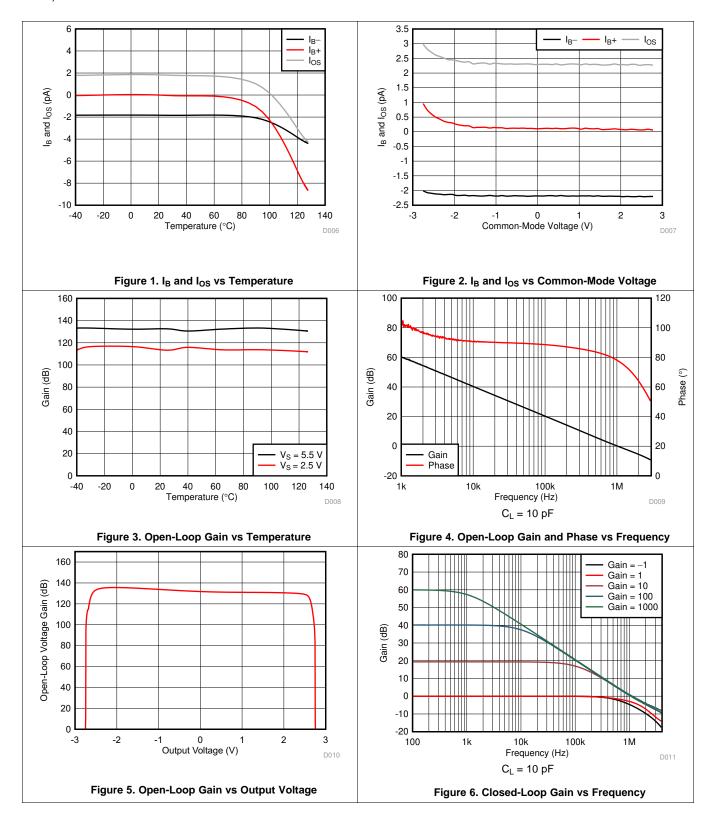
	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT			
OFFSET V	OLTAGE							
		Vs = 5 V	±1	±4				
V _{os}	Input offset voltage	Vs = 5 V, T _A = -40°C to 125°C		±5	mV			
dV _{os} /dT	V _{OS} vs temperature	$T_A = -40$ °C to 125°C	±1		μV/°C			
PSRR	Power-supply rejection ratio	$V_S = 2.5 \text{ to } 5.5 \text{ V}, V_{CM} = (V-)$	78 100		dB			
INPUT VOL	TAGE RANGE							
.,	Common-mode	No phase reversel will to will input	()/) 0.4	()(1) 4	V			
V _{CM}	voltage range	No phase reversal, rail-to-rail input	(V-) - 0.1	(V+) - 1	V			
	Common-mode	$\begin{split} V_S &= 2.5 \text{ V}, \text{ (V-)} - 0.1 \text{ V} < V_{CM} < \text{(V+)} - 1.4 \text{ V} \\ T_A &= -40 ^{\circ}\text{C} \text{ to } 125 ^{\circ}\text{C} \end{split}$	86					
		$V_S = 5.5 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) - 1.4 \text{ V}$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$						
CMRR	rejection ratio	$V_S = 5.5 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) + 0.1 \text{ V}$ $T_A = -40^{\circ}\text{C}$ to 125°C	63 77		dB			
		$V_S = 2.5 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) + 0.1 \text{ V}$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$	68					
INPUT BIAS	S CURRENT	1,4 = 10 0 10 120 0						
I _B	Input bias current	Vs = 5 V	±10		pA			
I _{os}	Input offset current		±10		pA pA			
los NOISE	mput onset culterit		±3		рA			
	Input voltage noise							
En	(peak-to-peak)	f = 0.1 Hz to 10 Hz, Vs = 5 V	5.1		μV_{PP}			
		f = 1 kHz, Vs = 5 V	33		\// 			
e _n	Input voltage noise density	f = 10 kHz, Vs = 5 V	30		nV/√ Hz			
'n	Input current noise density	f = 1 kHz, Vs = 5 V	25		fA/√Hz			
INPUT CAP	PACITANCE	+	+	-				
C _{ID}	Differential		1.5		pF			
C _{IC}	Common-mode		5		pF			
OPEN-LOO	OP GAIN			I.	-			
		$V_S = 5.5 \text{ V}, (V-) + 0.05 \text{ V} < V_O < (V+) - 0.05 \text{ V}, R_L = 10 \text{ k}\Omega$	100 115					
		$V_S = 2.5 \text{ V}, (V-) + 0.04 \text{ V} < V_O < (V+) - 0.04 \text{ V}, R_L = 10 \text{ k}\Omega$	98					
A _{OL}	Open-loop voltage gain	$V_S = 2.5 \text{ V}, (V-) + 0.1 \text{ V} < V_O < (V+) - 0.1 \text{ V}, R_L = 2 \text{ k}\Omega$	112		dB			
		$V_S = 5.5 \text{ V}, (V-) + 0.15 \text{ V} < V_O < (V+) - 0.15 \text{ V}, R_L = 2 \text{ k}\Omega$	128		†			
FREQUENC	CY RESPONSE	3						
GBW	Gain-bandwidth product	Vs = 5 V	1		MHz			
Pm	Phase margin	V _S = 5.5 V, G = 1	76		۰			
SR	Slew rate	Vs = 5 V	1.7		V/µs			
		To 0.1%, $V_S = 5 \text{ V}$, 2-V step , $G = +1$, $C_L = 100 \text{ pF}$	3		,,,,,			
ts	Settling time	To 0.01%, $V_S = 5 \text{ V}$, 2-V step , $G = +1$, $C_L = 100 \text{ pF}$	4		μs			
OR	Overload recovery time	$V_S = 5 \text{ V}, V_{IN} \times \text{gain} > V_S$	0.9		μs			
THD+N	Total harmonic distortion + noise	V _S = 5.5 V, V _{CM} = 2.5 V, V _O = 1 V _{RMS} , G = +1, f = 1 kHz, 80-kHz measurement BW	0.005%		μο			
OUTPUT								
	Veltara autorit	$V_{S} = 5.5 \text{ V}, R_{L} = 10 \text{ k}\Omega$	20	50				
Vo	Voltage output swing from supply rails	$V_S = 5.5 \text{ V}, R_L = 10 \text{ M}2$ $V_S = 5.5 \text{ V}, R_L = 2 \text{ k}\Omega$	40	75	mV			
	Short-circuit current	$V_S = 5.5 \text{ V}, R_L = 2 \text{ K} \Omega$ $V_S = 5.5 \text{ V}$	±40	13	mA			
sc 7	Open-loop output impedance		1200		Ω			
Z _o		Vs = 5 V, f = 1 MHz	1200		3.2			
POWER SU			2.5 (.4.25)	F F (. 0.75)				
V _S	Specified voltage range	L 0 A V 5 - 5 - V	2.5 (±1.25)	5.5 (±2.75)	V			
lα	Quiescent current per amplifier	$I_O = 0$ mA, $V_S = 5.5$ V $I_O = 0$ mA, $V_S = 5.5$ V, $T_A = -40^{\circ}$ C to 125°C	70	125 150	μΑ			
	Power-on time	$V_S = 0 \text{ V to 5 V, to } 90\% \text{ I}_Q \text{ level}$	50		μs			

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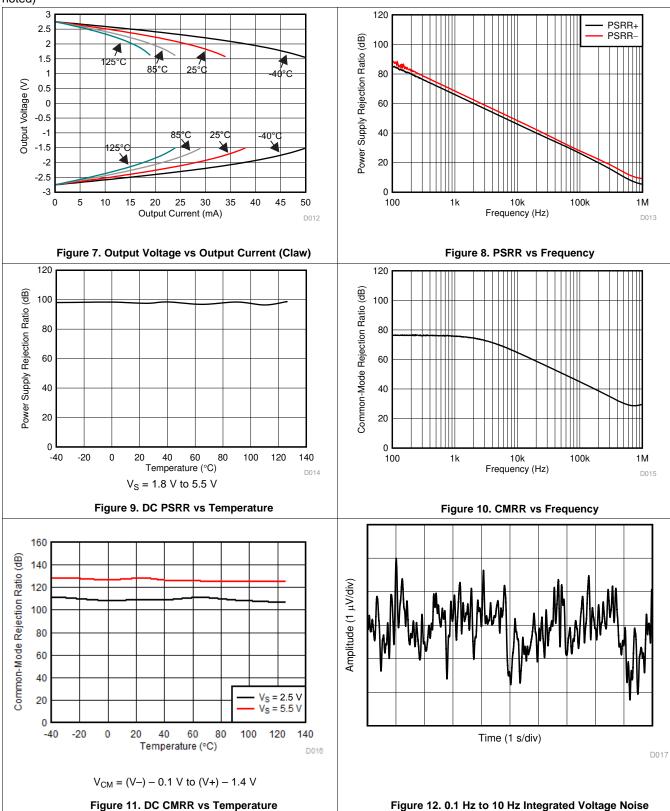
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6.8 Typical Characteristics

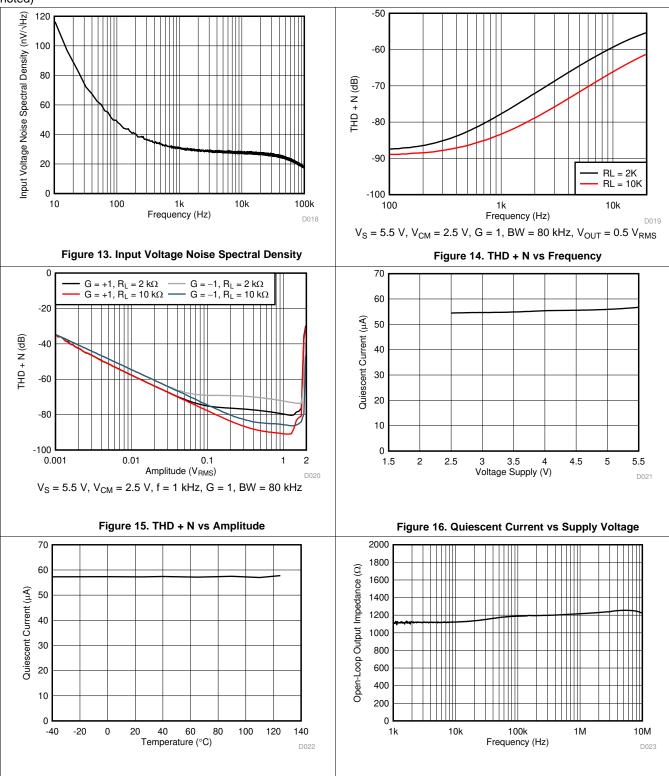








at T_A = 25°C, V+ = 2.75 V, V- = -2.75 V, R_L = 10 k Ω connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)



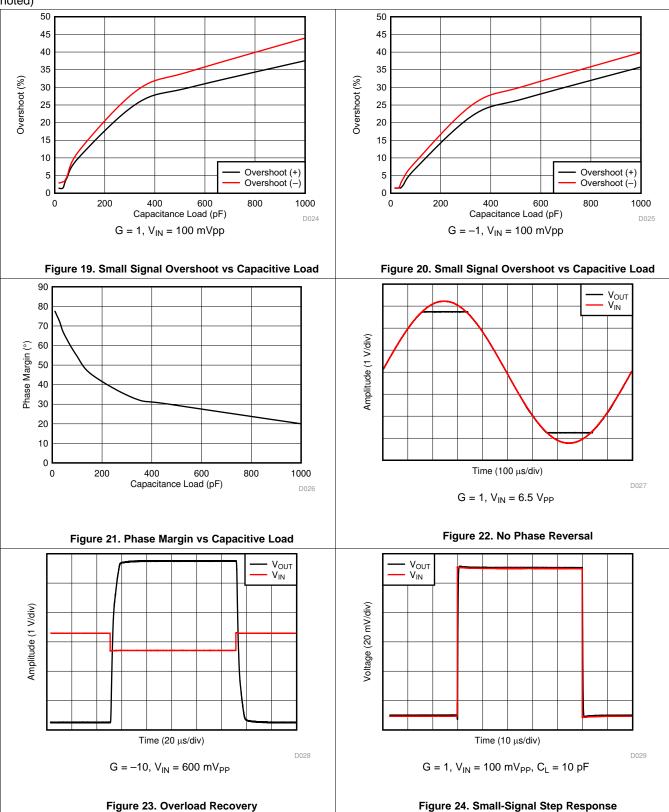
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Figure 17. Quiescent Current vs Temperature

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Figure 18. Open-Loop Output Impedance vs Frequency







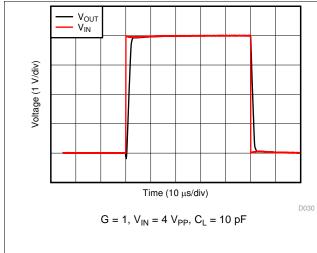
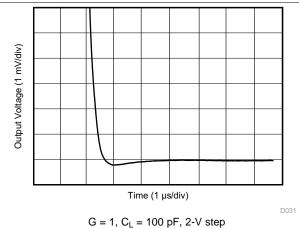


Figure 25. Large-Signal Step Response



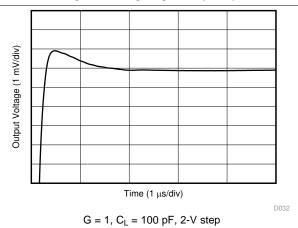


Figure 27. Large-Signal Settling Time (Positive)

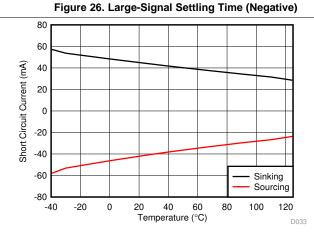


Figure 28. Short-Circuit Current vs Temperature

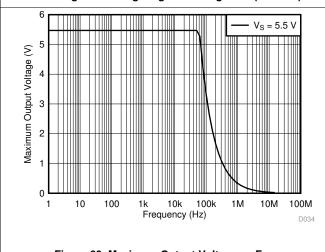


Figure 29. Maximum Output Voltage vs Frequency

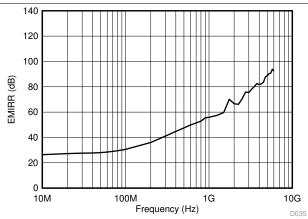
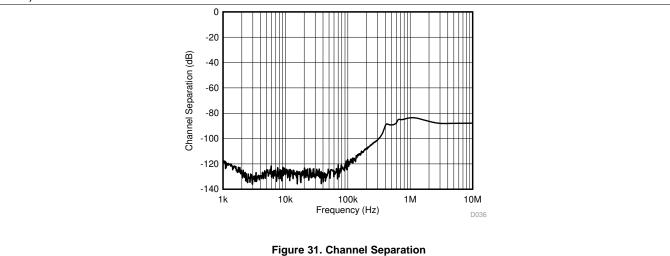


Figure 30. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR+) vs Frequency





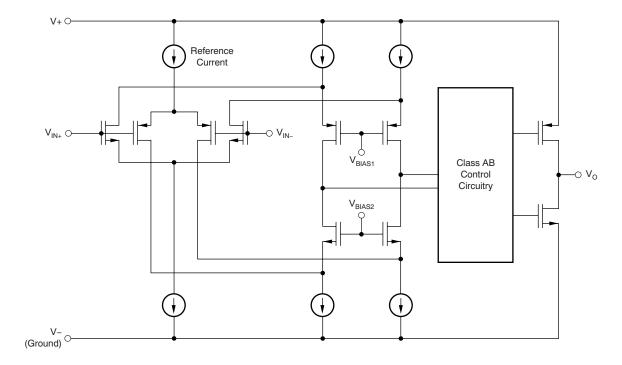


7 Detailed Description

7.1 Overview

The LMV3xxA is a family of low-power, rail-to-rail output op amps. These devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose applications. The input common-mode voltage range includes the negative rail and allows the LMV3xxA family to be used in many single-supply applications. Rail-to-rail output swing significantly increases dynamic range, especially in low-supply applications, and makes them suitable for driving sampling analog-to-digital converters (ADCs).

7.2 Functional Block Diagram



Product Folder Links: LMV321A LMV324A LMV358A



7.3 Feature Description

7.3.1 Operating Voltage

The LMV3xxA family of op amps are for operation from 2.5 V to 5.5 V. In addition, many specifications such as input offset voltage, quiescent current, offset current, and short circuit current apply from -40°C to 125°C. Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* section.

7.3.2 Input Common Mode Range

The input common-mode voltage range of the LMV3xxA family extends 100 mV beyond the negative supply rail and within 1 V below the positive rail for the full supply voltage range of 2.5 V to 5.5 V. This performance is achieved with a P-channel differential pair, as shown in the *Functional Block Diagram*. Additionally, a complementary N-channel differential pair has been included in parallel to eliminate issues with phase reversal that are common with previous generations of op amps. However, the N-channel pair is not optimized for operation. TI recommends limiting any voltages applied at the inputs to less than $V_{CC} - 1$ V to ensure that the op amp conforms to the specifications detailed in the *Electrical Characteristics* table.

7.3.3 Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the LMV3xxA family delivers a robust output drive capability. A class-AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 k Ω , the output swings to within 20 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

7.3.4 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return to the linear state. After the charge carriers return to the linear state, the device begins to slew at the specified slew rate. Therefore, the propagation delay (in case of an overload condition) is the sum of the overload recovery time and the slew time. The overload recovery time for the LMV3xxA family is approximately 850 ns.

7.4 Device Functional Modes

The LMV3xxA family has a single functional mode. The devices are powered on as long as the power-supply voltage is between 2.5 V (\pm 1.25 V) and 5.5 V (\pm 2.75 V).

Submit Documentation Feedback

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMV3xxA family of low-power, rail-to-rail output operational amplifiers is specifically designed for portable applications. The devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving less than or equal to 10-k Ω loads connected to any point between V+ and V−. The input common-mode voltage range includes the negative rail, and allows the LMV3xxA devices to be used in many single-supply applications.

8.2 Typical Application

8.2.1 LMV3xxA Low-Side, Current Sensing Application

Figure 32 shows the LMV3xxA configured in a low-side current sensing application.

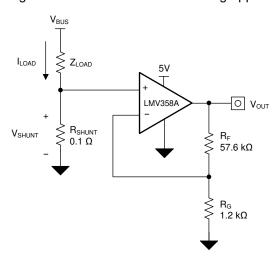


Figure 32. LMV3xxA in a Low-Side, Current-Sensing Application

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8.2.1.1 Design Requirements

The design requirements for this design are:

Load current: 0 A to 1 AOutput voltage: 4.9 V

Maximum shunt voltage: 100 mV

8.2.1.2 Detailed Design Procedure

The transfer function of the circuit in is given in Equation 1.

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times Gain$$
 (1)

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is shown using Equation 2.

$$R_{SHUNT} = \frac{V_{SHUNT_MAX}}{I_{LOAD_MAX}} = \frac{100mV}{1A} = 100m\Omega$$
 (2)

Using Equation 2, R_{SHUNT} is calculated to be 100 m Ω . The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the LMV3xxA to produce an output voltage of approximately 0 V to 4.9 V. The gain needed by the LMV3xxA to produce the necessary output voltage is calculated using Equation 3.

$$Gain = \frac{\left(V_{OUT_MAX} - V_{OUT_MIN}\right)}{\left(V_{IN_MAX} - V_{IN_MIN}\right)}$$
(3)

Using Equation 3, the required gain is calculated to be 49 V/V, which is set with resistors R_F and R_G . Equation 4 sizes the resistors R_F and R_G , to set the gain of the LMV3xxA to 49 V/V.

$$Gain = 1 + \frac{(R_F)}{(R_G)}$$
(4)

Selecting R_F as 57.6 $k\Omega$ and R_G as 1.2 $k\Omega$ provides a combination that equals 49 V/V. Figure 33 shows the measured transfer function of the circuit shown in Figure 32. Notice that the gain is only a function of the feedback and gain resistors. This gain is adjusted by varying the ratio of the resistors and the actual resistors values are determined by the impedance levels that the designer wants to establish. The impedance level determines the current drain, the effect that stray capacitance has, and a few other behaviors. There is no optimal impedance selection that works for every system, you must choose an impedance that is ideal for your system parameters.

8.2.1.3 Application Curve

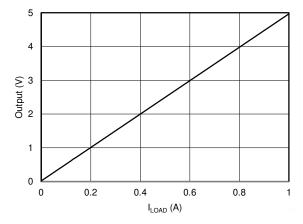


Figure 33. Low-Side, Current-Sense Transfer Function



8.2.2 Single-Supply Photodiode Amplifier

Photodiodes are used in many applications to convert light signals to electrical signals. The current through the photodiode is proportional to the photon energy absorbed, and is commonly in the range of a few hundred picoamps to a few tens of microamps. An amplifier in a transimpedance configuration is typically used to convert the low-level photodiode current to a voltage signal for processing in an MCU. The circuit shown in Figure 34 is an example of a single-supply photodiode amplifier circuit using the LMV358A.

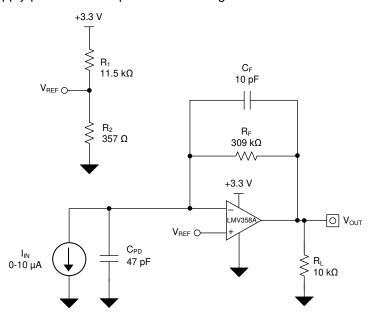


Figure 34. Single-Supply Photodiode Amplifier Circuit



8.2.2.1 Design Requirements

The design requirements for this design are:

Supply voltage: 3.3 V Input: 0 µA to 10 µA Output: 0.1 V to 3.2 V Bandwidth: 50 kHz

8.2.2.2 Detailed Design Procedure

The transfer function between the output voltage (V_{OUT}), the input current, (I_{IN}) and the reference voltage (V_{REF}) is defined in Equation 5.

$$V_{OUT} = I_{IN} \times R_F + V_{REF}$$
 (5)

Where:

$$V_{REF} = V_{+} \times \left(\frac{R_1 \times R_2}{R_1 + R_2}\right) \tag{6}$$

Set V_{RFF} to 100 mV to meet the minimum output voltage level by setting R1 and R2 to meet the required ratio calculated in Equation 7.

$$\frac{V_{REF}}{V_{+}} = \frac{0.1 \text{ V}}{3.3 \text{ V}} = 0.0303 \tag{7}$$

The closest resistor ratio to meet this ratio sets R1 to 11.5 k Ω and R2 to 357 Ω .

The required feedback resistance can be calculated based on the input current and desired output voltage.

$$R_{F} = \frac{V_{OUT} - V_{REF}}{I_{IN}} = \frac{3.2 \text{ V} - 0.1 \text{ V}}{10 \text{ }\mu\text{A}} = 310 \frac{\text{kV}}{\text{A}} \approx 309 \text{ k}\Omega \tag{8}$$

Calculate the value for the feedback capacitor based on R_F and the desired -3-dB bandwidth, (f_{-3dB}) using Equation 9.

$$C_F = \frac{1}{2 \times \pi \times R_F \times f_{-3dB}} = \frac{1}{2 \times \pi \times 309 \text{ k}\Omega \times 50 \text{ kHz}} = 10.3 \text{ pF} \approx 10 \text{ pF}$$
(9)

The minimum op amp bandwidth required for this application is based on the value of R_F, C_F, and the capacitance on the INx- pin of the LMV358A which is equal to the sum of the photodiode shunt capacitance, (CPD) the common-mode input capacitance, (CCM) and the differential input capacitance (CD) as Equation 10 shows.

$$C_{IN} = C_{PD} + C_{CM} + C_D = 47 \text{ pF} + 5 \text{ pF} + 1 \text{ pF} = 53 \text{ pF}$$
 (10)

The minimum op amp bandwidth is calculated in Equation 11.

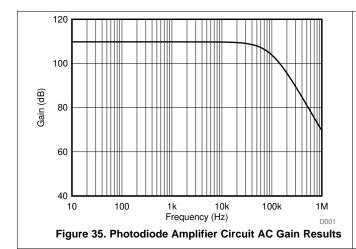
$$f_{=BGW} \ge \frac{C_{IN} + C_F}{2 \times \pi \times R_F \times {C_F}^2} \ge 324 \text{ kHz}$$
 (11)

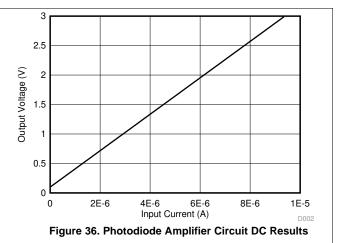
The 1-MHz bandwidth of the LMV3xxA meets the minimum bandwidth requirement and remains stable in this application configuration.



8.2.2.3 Application Curves

The measured current-to-voltage transfer function for the photodiode amplifier circuit is shown in Figure 35. The measured performance of the photodiode amplifier circuit is shown in Figure 36.







9 Power Supply Recommendations

The LMV3xxA family is specified for operation from 2.5 V to 5.5 V (±1.25 V to ±2.75 V); many specifications apply from -40°C to 125°C. The Typical Characteristics section presents parameters that may exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 6 V may permanently damage the device; see the Absolute Maximum Ratings table.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce coupling errors from noisy or highimpedance power supplies. For more detailed information on bypass capacitor placement, see the Layout Guidelines section.

9.1 Input and ESD Protection

The LMV3xxA family incorporates internal ESD protection circuits on all pins. For input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA. Figure 37 shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.

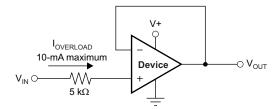


Figure 37. Input Current Protection

22

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10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power connections of the board and propagate to the power pins of the op amp itself. Bypass capacitors are used to reduce the coupled noise by providing a low-impedance path to ground.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is adequate for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground
 planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise
 pickup. Take care to physically separate digital and analog grounds, paying attention to the flow of the
 ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace at a 90 degree angle is much better as opposed to running the traces in parallel with the noisy trace.
- Place the external components as close to the device as possible, as shown in Figure 39. Keeping R_F and R_G close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring may significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the
 plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is
 recommended to remove moisture introduced into the device packaging during the cleaning process. A
 low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.2 Layout Example

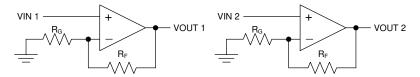


Figure 38. Schematic Representation for Figure 39

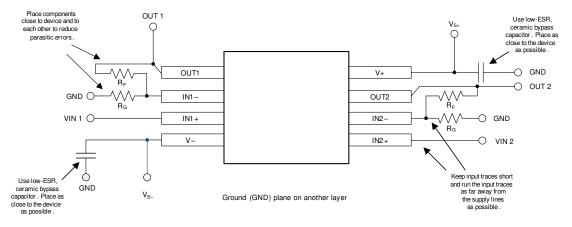


Figure 39. Layout Example

Product Folder Links: LMV321A LMV324A LMV358A



11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation, see the following:

Texas Instruments, EMI Rejection Ratio of Operational Amplifiers

11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LMV321A	Click here	Click here	Click here	Click here	Click here
LMV358A	Click here	Click here	Click here	Click here	Click here
LMV324A	Click here	Click here	Click here	Click here	Click here

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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11.5 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

Product Folder Links: LMV321A LMV324A LMV358A





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV321AIDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	10IF	Samples
LMV321AIDCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	1C2	Samples
LMV321AUIDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1WOF	Samples
LMV324AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LMV324	Samples
LMV324AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	LMV324A	Samples
LMV358AIDDFR	ACTIVE	SOT-23-THIN	DDF	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	358A	Samples
LMV358AIDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1MAX	Samples
LMV358AIDGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1MAX	Samples
LMV358AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	MV358A	Samples
LMV358AIPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	LMV358	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

6-Feb-2020

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

www.ti.com 17-Apr-2020

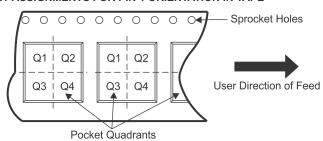
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV321AIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321AIDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321AUIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV324AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324AIDR	SOIC	D	14	2500	330.0	15.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV324AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV358AIDDFR	SOT- 23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV358AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358AIDGKT	VSSOP	DGK	8	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358AIDR	SOIC	D	8	2500	330.0	15.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358AIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

www.ti.com 17-Apr-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321AIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV321AIDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
LMV321AUIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV324AIDR	SOIC	D	14	2500	367.0	367.0	38.0
LMV324AIDR	SOIC	D	14	2500	336.6	336.6	41.3
LMV324AIPWR	TSSOP	PW	14	2000	366.0	364.0	50.0
LMV358AIDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
LMV358AIDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
LMV358AIDGKT	VSSOP	DGK	8	250	366.0	364.0	50.0
LMV358AIDR	SOIC	D	8	2500	336.6	336.6	41.3
LMV358AIPWR	TSSOP	PW	8	2000	366.0	364.0	50.0



SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE

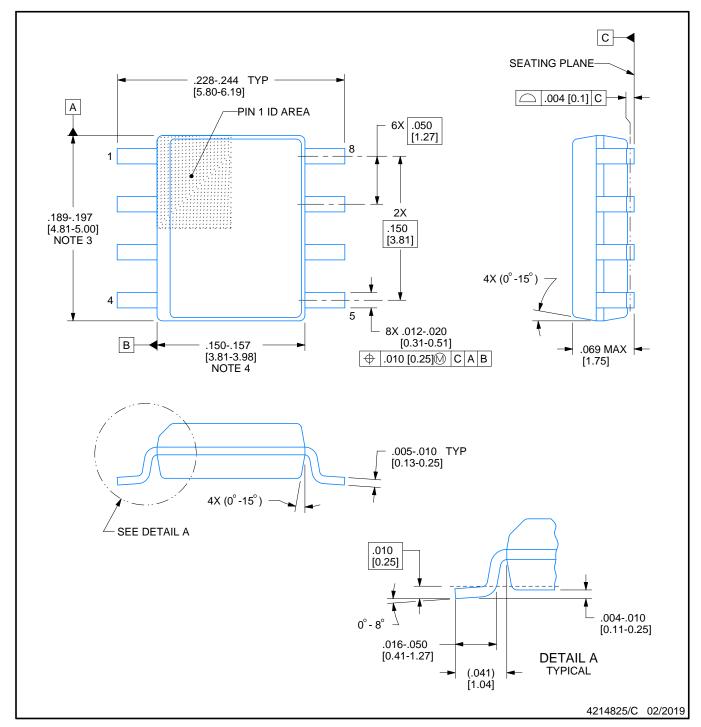


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT

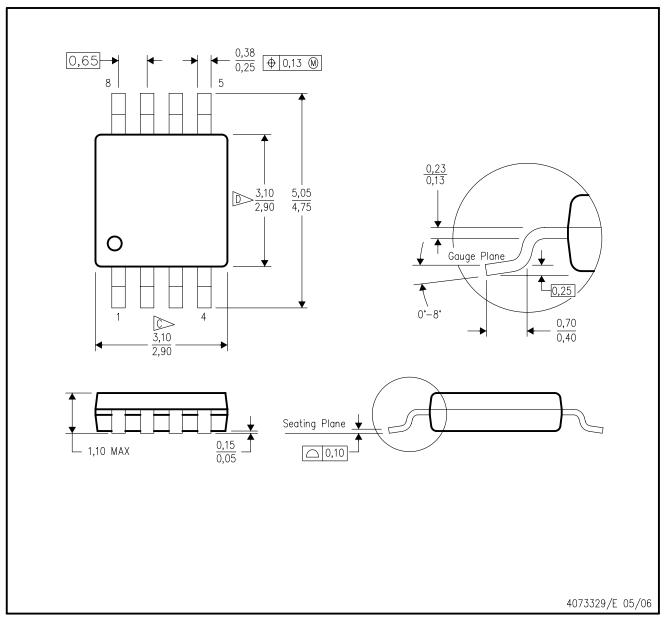


- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

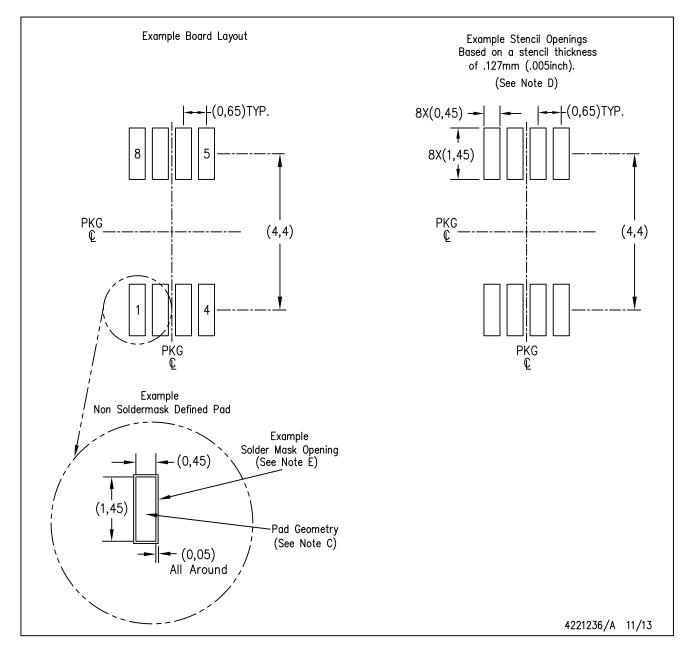


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE

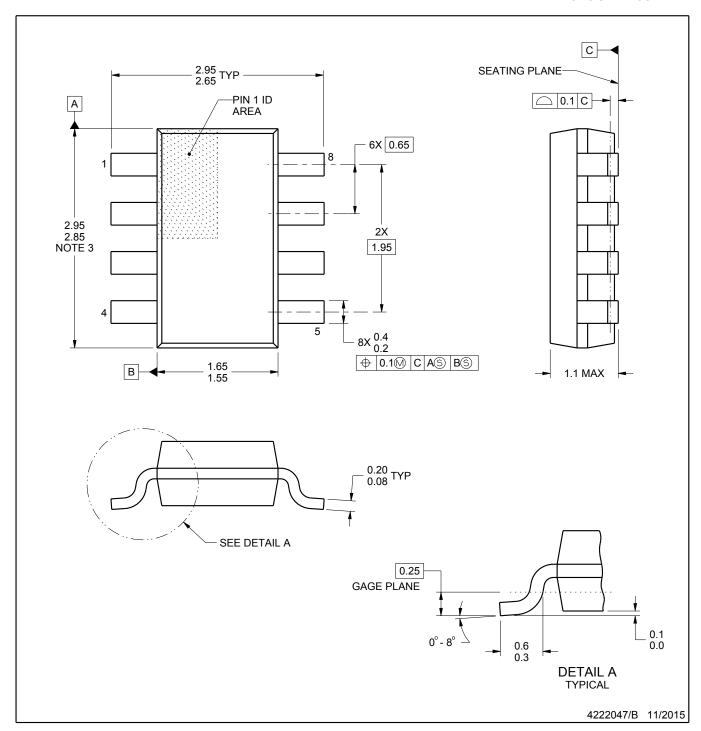


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





PLASTIC SMALL OUTLINE



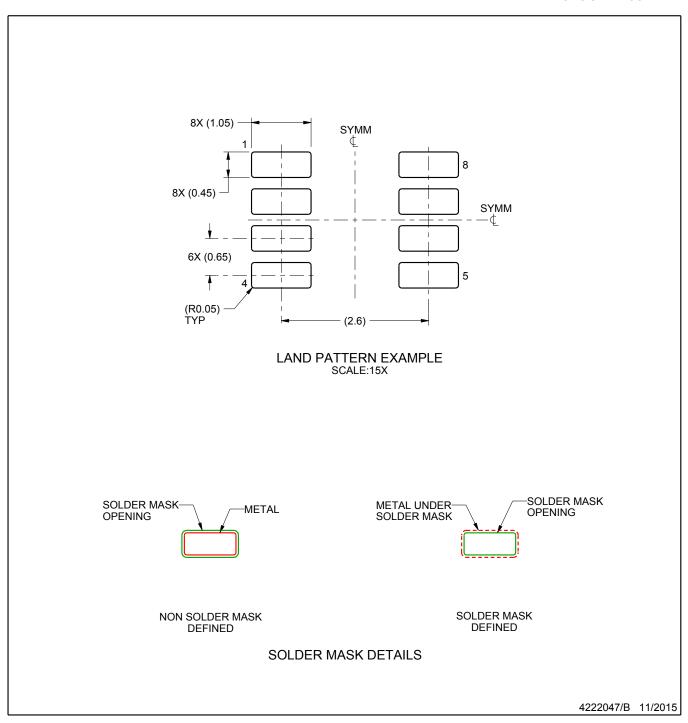
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



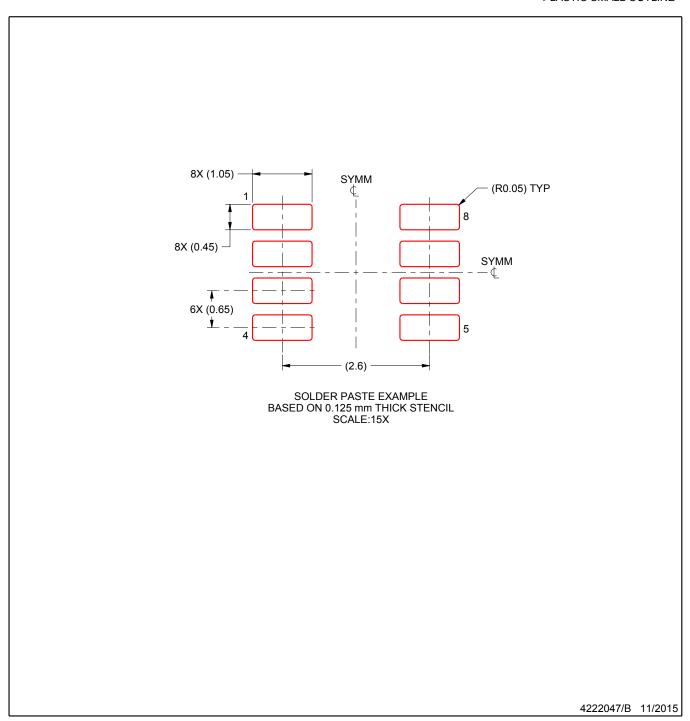
PLASTIC SMALL OUTLINE



- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



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